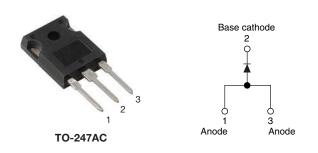
## VS-65PQ015PbF, VS-65PQ015-N3

**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 65 A



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PRODUCT SUMMARY							
Package	TO-247AC						
I <sub>F(AV)</sub>	65 A						
V <sub>R</sub>	15 V						
V <sub>F</sub> at I <sub>F</sub>	0.46 V						
I <sub>RM</sub> max.	870 mA at 100 °C						
T <sub>J</sub> max.	125 °C						
Diode variation	Single die						
E <sub>AS</sub>	9 mJ						

### FEATURES

- 125 °C T<sub>J</sub> operation ( $V_R < 5 V$ )
- Single diode configuration
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



- RoHS COMPLIANT HALOGEN
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and gualified according to JEDEC-JESD47
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-65PQ015... Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform	65	А						
V <sub>RRM</sub>		15	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1500	А						
V <sub>F</sub>	65 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.46	V						
TJ	Range	- 55 to 125	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VS-65PQ015PbF	VS-65PQ015-N3	UNITS				
Maximum DC rovorce voltage	ge V <sub>R</sub>	T <sub>J</sub> = 100 °C	15	15	V				
Maximum DC reverse voltage		T <sub>J</sub> = 125 °C	5	5	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 83 °C, r	65						
Maximum peak one cycle	leave.	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	1500	A				
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	400					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 4.5 m⊦	9	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by $T_{\rm J}$ maximu	2	А					

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ELECTRICAL SPECIFICATIONS
ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		65 A	T <sub>.1</sub> = 25 °C	0.50		
Forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	130 A	1j=25 C	0.71	v	
	VFM ()	65 A	T <sub>.1</sub> = 125 °C	0.46	v	
		130 A	1j = 125 C	0.76		
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = 5 V	1.2	А	
Reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	18	mA	
		T <sub>J</sub> = 100 °C	$v_{\rm R} = naleu v_{\rm R}$	870	IIIA	
Threshold voltage	V <sub>F(TO)</sub>	T T maximum		0.137	mV	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		4.9	mΩ	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz) 25 °C	4300	pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	Measured lead to lead 5 mm from package body			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		- 55 to 125	°C				
Maximum storage temperature range	T <sub>Stg</sub>		- 55 to 150					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	0.8	°0111				
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Nounting surface, smooth and greased		°C/W				
Approvimeto weight			6	g				
Approximate weight			0.21	oz.				
Mounting torgue		Non-lubricated threads	6 (5)	kgf ⋅ cm				
Mounting torque maximum	1	Non-Iudricated trireads	12 (10)	(lbf · in)				
Marking device		Case style TO-247AC (JEDEC)	65P0	Q015				



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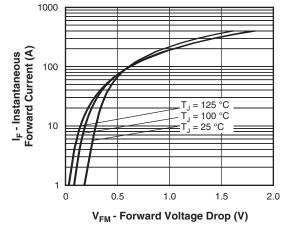


Fig. 1 - Maximum Forward Voltage Drop Characteristics

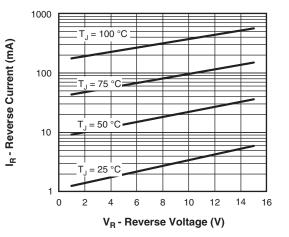


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

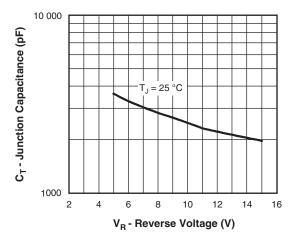
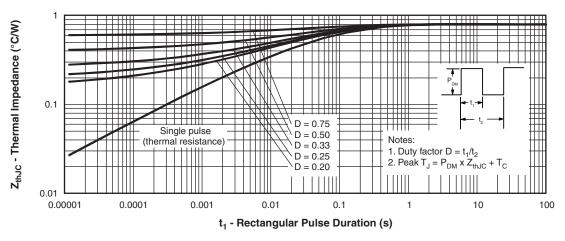


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





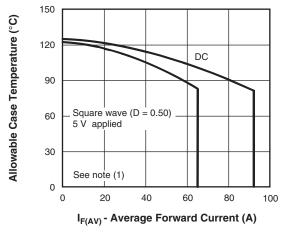
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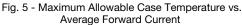
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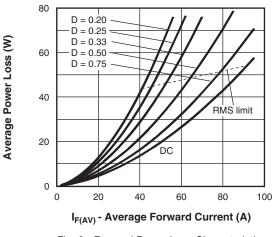
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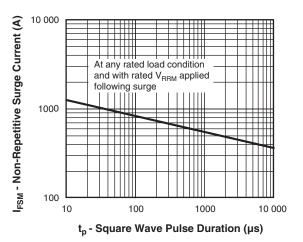


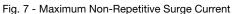
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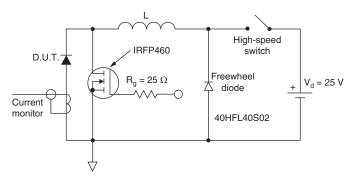














#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = 5 \mbox{ V} \end{array}$

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ad (Pb)-free and RoHS compliant • -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-65PQ015PbF	25	500	Antistatic plastic tube						
VS-65PQ015-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95226					
	TO-247AC modified -N3	www.vishay.com/doc?95007					
SPICE model		www.vishay.com/doc?95306					

VS-65PQ015PbF, VS-65PQ015-N3

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### **ORDERING INFORMATION TABLE**

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	IADEE	•					
Device code	VS-	65	Р	Q	015	PbF	
	1	2	3	4	5	6	•
	1 - 2 - 3 -	Curi Pac	nay Sem rent ratir kage: TO-247		•	duct	
	4 -	Sch	ottky "Q	" series			
	5 -	Volt	age cod	e (015 =	= 15 V)		
	6 -	Env	ironmen	ital digit			
		• P	bF = Le	ad (Pb)-	-free and	d RoHS	со

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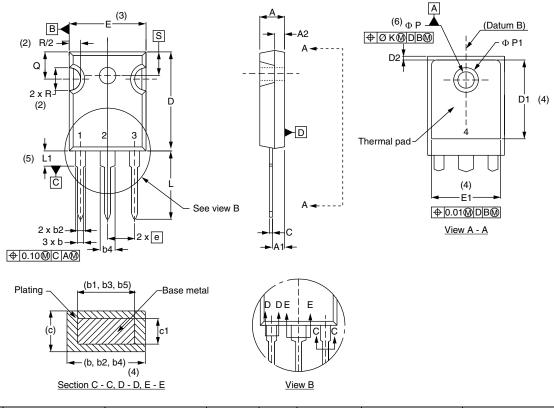
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TO-247AC - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS INCHES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054		E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055		е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053		ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094		L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133		Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035		Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033		R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4						

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension c and Q

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